Encloyd

FAIRCHILD R&D LIBRARY PALD AND, CALIFORNIA

Birli

COMPANY PRIVATE - Not to be reproduced or disclosed to nonemployees without express written consent from Director's Office.

Copy No. 105

FAIRCHILD RESEARCH & DEVELOPMENT

LIST OF TECHNICAL MEMORANDUMS

This Title report is Company Private and <u>must</u> be returned to the R&D Library by the individual to whom the above number is assigned.

All reports printed after 1 March 1968 are Company Private unless they have had an outside publication.

Reports prior to 1 March 1968 that have an * appearing before the listing are considered Company Private.

2

TECHNICAL MEMORANDUMS

COMPANY PRIVATE - Not to be reproduced or disclosed to nonemployees without express written consent from Director's Office.

<u>NO.</u>	TITLE	AUTHOR	DATE
1	Electrode Assembly for Anodization of Semiconductors	E. Duffek E. Benjamini	4/2/63
2	Techniques Related to Fine-Line Metal Etching	S. Fok	4/25/63
3	A Procedure for Preparing Minute Amounts of Material for Powder Diffraction	P. Peterson J. Lawrence	4/8/63
4	Gevaert Plates	C. Van Ness	3/25/63
5	Alternate Source of Arsenic Doping	K. Lemons	5/8/63
6	Microhardness Measurement	W. Wandry P. Peterson	4/17/63
7	Ozone from Xenon Ultraviolet Lamp, Metallograph Light Source	B. Yurash	5/10/63
8	Particle Count, Oronite Acetone	B. Yurash	5/10/63
9	Decrease of Capacitance of Anodix Oxide Capacitors with Field	A. Lewis	5/16/63
10	The Estimation of the Low Current Beta of the YP3 Phototransistor Without a Base Contact	R. Dyck	3/22/63
11	The Effect of Aluminum on YP3 Phototransistor Baked for One Hour at 500°C in Nitrogen	R. Dyck	5/13/63
12	Examination of Mask Samples Projection Printed by M. J. Barrett of Utah	S. Fok C. Van Ness	5/27/63
13	Computer Program to Calculate the Impurity Distribution from Differential Capacitance Measurements	A. Grove	5/21/63
14	The Effect of Aluminum on YP3 Phototransistors	G. Weckler	7/1/63
15	V/I Meter	J. McPhail	7/3/63
16	Fume Survey - 1963	B. Yurash	7/22/63
17	Residual Gases in Vacuum Evaporators	R. Waits	7/18/63
18	Etching Machine Evaluation Report	L. Gille	1/22/63
19	San Rafael FD 200 Low Breakdown	J. Lawrence	8/6/63
20	Tuning a Microwave Series Diode Switch	R. Orrick	8/8/63
			0,0,00

TECHNICAL MEMORANDUMS		consent from Dilector's office.	
	CAL MEMORAN DUMS	AUTHOR	DATE
<u>NO</u> . 21	Thin Film Memory Circuit Design - Address Register	J. Schmidt	8/23/63
22	Thin Film Memory Circuit Design - Drivers	J. Friedrich	8/30/63
23	Base Periphery Pipe (Anomalous Soft Type)	J. Lawrence	9/4/63
24	Thin Film Memory Circuit Design - Timing Cable Driver	J. Schmidt	9/11/63
25	Sense Amplifier Design for Proposed Thin Film Memory	H. Zinschlag	9/10/63
26	Thin Film Memory Circuit Design - Logic	J. Friedrich	9/18/63
27	Thin Film Memory - Summary of Organization	J. Schmidt	9/20/63
28	Metallographic Comparison of Two Glass to Metal Fusing Processes	B. Yurash J. Dahl W. Wandry	9/20/63
	Design of Nichrome Resistors	R. Waits	9/26/63
29 30	Transducer Performance as Dependent on Doping Level	N. Pearson W. Lafky	9/26/63
(31)	Background Information for Machine Retrieval of Co-ordinate Indexing	C. McAllister	10/28/63
32	Fluoride Analysis in Ambient Air by the Limed Paper Method	B. Yurash M. Gilbert W. Jiminez	10/31/63
33	Relevancy and Current Value of Stored Information	W. Waring	10/29/63
34	Argon Quality vs Film Formation in Crystal Growing	E. Friberg B. Yurash	11/6/63
35	Analysis of Air in the Phosphorus Predeposition Room, Transistor Manufacturing	B. Yurash	11/14/63
36	DISO Amplifier	J. McPhail	11/22/63
(37)	Pnp Diffused Pipe	J. Lawrence	11/26/63
38	Micro-Fax Step and Repeat Camera and Other Commercially Available Units	S. Fok	11/26/63
39	Analysis of Air Samples at Diode Manufacturing at San Rafael	B. Yurash	12/11/63

FAIRCHILD R&D

-

1

.

D

1

1. 1.

COMPANY PRIVATE – Not to be reproduced or disclosed to nonemployees without express written consent from Director's Office.

TECHN	I CAL MEMORANDUMS	consent from Director	's Office.
<u>NO</u> .	TITLE	AUTHOR	DATE
40	The Structure of Silicon Films Deposited on Thick Oxides - X-Ray Analysis	J. Lawrence	12/13/63
41	A Technique of Silicon Die-Attach for Minimum Au-Si Penetration	L. Ornik	12/6/63
42	Clean Oxidation Systems	P. Flint	12/11/63
43	Analysis of Air in Wafer Fabrication Area 3, Transistor Manufacturing	B. Yurash	12/23/63
44	Investigation of Potting Materials Used in the Manufacturing of GE 2N2711 or 2N2714	K. Lemons	12/23/63
45	Temperature Co-efficients of Some Glass Package Diodes	C. T. Sah	1/20/64
46	A Comparison of Two FD200 Wafers; Standard Process vs New Fabrication Process Using a 7 Micron Grit and a DB Etch	J. Lawrence	1/2/64
47	Purging HCl Cylinders	H. Wigton	12/6/63
48	Master Curves of HH _{FE} vs Ic at 25° for Several Fairchild Mesa and Planar Transistors	C. T. Sah	1/23/64
49	Experimental Data on the Variation of HHFE with Temperature and Collector Current	C. T. Sah	3/9/61
50	Ic vs V _{CC} Characteristic Families at 4.2°K, 77°K, and 300°K of an npn Fairchild Transistor (1240)	C. T. Sah	8/1/59
51	Effect of Epitaxial Film Thickness on 6206 Transistor Parameters	G. Steres	1/22/64
52	Seminar by D. R. Young (IBM Components) on the Use of MOS Devices to Study Passivated Surfaces - Stanford, January 30, 1964	A. Grove B. Deal E. Snow	2/4/64
53	Evaluation of Drying Units	B. Deal	2/6/64
54	Deposition of Smooth Glass Film on Silicon Wafers	M. Dumesnil	2/12/64
55	Oxidation of Epitaxial Wafers in an Epitaxial Reactor	J. Schroeder	2/11/64
56	Horizontal Rotary Reactor - Rotation and the Thickness Variation Due to Depletion	A. Davis	2/12/64

COMPANY PRIVATE - Not to	be
reproduced or disclosed to no	n-
employees without express writt	en
consent from Director's Office.	

TECHNICAL MEMORANDUMS		consent from Director's Office.	
NO.	TITLE	AUTHOR	DATE
57	Abrasion Resistant Aluminum Metallization	M. Jumesnil	2/25/64
58	Boron Masking Curves	A. Grove	2/28/64
59	1702 Epitaxy Material	R. Tucker	2/27/64
60	Surface Investigation of Various Copper Substrates and Magnetic Matrixes	H. Koehler	2/28/64
61	The Light Spot Probe	R. Dyck	3/3/64
62	The Effects of Fast-Neutron Radiation on the MOST - Initial Experimental Results	D. Fitzgerald	3/4/64
63	The Effect of Fast Neutron Radiation on Silicon Controlled Rectifiers - Initial Experimental Results	D. Fitzgerald	3/4/64
64	Evaluation of Several Sertl Etches for Stacking Faults and Dislocations	J. Dahl W. Wandry	3/9/64
65	Thalium Oxide Solder Glass	M. Dumesnil	3/10/64
66	An Anomalous Negative Resistive "Base Collector" Characteristic	R. Dyck	3/16/64
67	Electrical Irregularities in npn and pnp Devices Resulting from Tweezer Metallic Contamination	J. Lawrence	3/16/64
68	Distillation of Silicon Tetrachloride	J. Gordon	3/24/64
69	Photodecoder Step and Repeat Camera Tape Reader	A. Nyfeler	3/20/64
70	The Infrared Interference Technique of Epitaxial Film Measurement Applied to Micrologic and Other High Resistivity Substrates	A. Davis	4/16/64
71	Preliminary Report - Investigation of Failure-Mode of Circuit Interconnections Used in the "Pacemaker" Cardiac Pulser	K. Lemons	3/30/64
72	Bias Tee, 0.5 - 3.0 Gc, Model One	R. Orrick	4/7/64
73	Photolithography Alternatives for Large Integrated Systems	L. Gille S. Fok	4/10/64
74	A Simple Test Pattern Designed to Check Step and Repeat Accuracy in Microelectronics	S. Fok	4/13/64

0

C

3

TECHNICAL MEMORANDUM

COMPANY PRIVATE - Not to be reproduced or disclosed to nonemployees without express written consent from Director's Office.

TECHN	ICAL MEMORANDUM	Consent from Directors	
NO.	TITLE	AUTHOR	DATE
75	A Method of Thinning Large Regions of (111) Silicon Crystals to Thicknesses Less Than 1000 Å for Surface Imperfection Studies	J. Lawrence H. Koehler	4/1/64
76	Silver Migration	J. Dahl	4/23/64
77	Electrical Irregularities in pnp and npn Devices Resulting from Tweezer Metallic Contamination - Part II	J. Lawrence	4/24/64
78	The Difference Between the Infrared Inter- ference and Stacking Fault Techniques in the Measurement of Epitaxial Film Thickness	A. Davis	4/30/64
79	Delineation of Junctions Between Epitaxial Films and Substrates in GaAs	E. Meieran	5/4/64
80	Glass Binding Technique as it Applies to PT Series Pressure Transducer Diaphragm- Ring Assembly	B. Phy	5/14/64
81	Electrical Irregularities on the 1713 Device	J. Lawrence	5/18/64
82	The Micrologic Bonds - Off Problem	J. Dahl	5/20/64
83	A Preliminary Literature Survey Concerning MoSi2 and Related Compounds	C. Bittmann C. McAllister	5/20/64
84	Proposed System for Extremely Rapid Production of Complex Photomasking	L. Gille	6/12/64
85	"Selectron Plating Evaluation"	E. Armstrong	6/15/64
86	Copper Plated Through Hole Circuit Board Manufacture - Prototype Quantities	E. Armstrong	6/15/64
87	Hot Cone Bonding	P. Ullman	6/17/64
88	EBIC Diode Assembly	P. Ullman	6/29/64
89	Braze Alloy for Flip-Chip Assembly	J. Dahl	7/2/64
90	Surface Lattice Disorders - Not Mechanically Induced	J. Lawrence	7/9/64
91	Resist Masking Process Procedure Employed for the 0039 Device	G. Blome	7/15/64
92	Prototype Printed Circuits Design and Fabrication Process from Logic Diagrams to Completed Board	W. R. Smith	7/7/64

	IILD R&D ICAL MEMORANDUMS	COMPANY PRIVATE – Not to be reproduced or disclosed to non employees without express written consent from Director's Office.	
NO.	TITLE	AUTHOR	DATE
93	An Evaluation of Organic Vehicles for Screen Printing Solder Glasses	E. Kanazawa	7/27/64
94	Source to Drain Resistance Beyond Pinchoff in Metal-Oxide-Semiconductor Transistors (MOST)	G. Reddi	7/27/64
95	Reactive Sputtering of Au/Cu in Oxygen	W. Lehrer	8/10/64
96	Subsystem Evaluation of the CTL Circuit	W. R. Smith	8/14/64
97)	Fume Survey 1964	B. Yurash B. Jiminez	8/14/64
98	The SCR Device's Soft and Short Junction Defect	J. Lawrence	8/17/64
99	Cancelled		
*100	R&D Photoresist Process Flow	G. Blome A. Engvall S. Fok	10/26/64
101	Electroless Nickel Plating for Solder Die Attach	B. Phy	9/18/64
102	Beryllia TO-5 Package	W. Steffe	9/28/64
103	Photoresist Removal of Metal and Oxide Films	J. Campbell	10/5/64
104	Prototype Printed Circuit Board Process Flow - Artwork Reduction	S. Fok	10/1/64
105	Collector Region Impurity Profile of Integrated npn Transistor Having Buried Antimony Layers	A. Slobodsky	10/1/64
106	Soft Solder Die Attach	B. Phy	10/7/64
107	Recommended Heat Flow Tests for Integrated Circuit Packages	R. Rice	10/7/64
108	Cancelled		
109	Experiments to Improve the A-C Stability of the CTL Family	L. Vadasz	10/9/64
110	History of Evaporation of Alumina Within Fairchild	J. Campbell	10/23/64
111	Mechanical Polishing of Surf Devices	D. Pilling C. Hart	11/16/64
	-6-		

COMPANY PRIVATE - Not to be

TECHNICAL MEMORANDUMS		consent from Director	's Office.
NO.	TITLE	AUTHOR	DATE
112	Optical Capabilities of R&D Mask Making Cameras	S. Fok	11/16/64
113	Ultrasonic Separator of Large Area Silicon Devices	G. Daughters	11/13/64
114	FD-Series Lattice "Microcracks", A Possible Cause of Low Breakdown and Shorts	J. Lawrence	12/15/64
115	Measurement of Epitaxial Silicon Films by Infrared Reflectance Measurements	A. Lewis	12/8/64
116	Ozone in Smog as a Cause of KPR Scum	A. Engvall	12/8/64
117	Multi-Island Ceramic Flatpak Header	E. Kanazawa	12/9/64
118	Precision Cutting Large Area Devices from Silicon Wafers	H. Borden	12/14/64
119	The Use of HBr in Place of HCl as a Substrate Etchart in the Epitaxial Reactors	E. Yim	12/23/64
120	Electron Microscopy at Fairchild Semiconductor	H. Koehler	11/18/64
121	Preliminary Study of X-Ray Effects on MOST Structures	E. Snow	1/12/65
122	Unidimensional Drawing in Microcircuits	S. Fok	11/19/64
123	Competitive Light Sensor: TI LSX 600; npn Planar Silicon Light Sensor	R. Dyck	1/28/65
124	Analysis of Electrical Defects Due to Wafer Contamination	J. Lawrence	2/25/65
125	A Comparison of the "Dust" Problem in Positive Pressure Clean Hoods vs a "Normal" Hood	B. Yurash	2/22/65
126	Beryllium in Air and Wipe Samples	B. Yurash	3/4/65
127	Disposal of Cyanide Wastes	B. Yurash	3/16/65
128	Scratch Resistance Testing of Thin Films	R. Waits	3/17/65
129	Effect of X-Irradiation on P-Channel MOSTs	A. Grove A. Ballonoff J. Kelley	3/19/65

.'

0

C

1 in to

FAIRCHILD R&D

...

C

0

COMPANY PRIVATE – Not to be reproduced or disclosed to nonemployees without express written consent from Director's Office.

TECHNICAL MEMORANDUMS		consent from Director's Office.	
NO.	TITLE	AUTHOR	DATE
130	Predeposition, Induced, Surface Lattice Disorder	J. Lawrence	3/26/65
131	Nickel Plating 7/16" Copper Studs - Source Mitronics Company	E. Duffek	4/1/65
132	Air Quality in Header Plating Shop, Transistor Manufacturing	B. Yurash	4/12/65
133	D.I. Water Control Analyses	B. Yurash	4/15/65
134	Digital Data Photo-Diode Amplifier	H. Murphy	4/26/65
135	Calculation of Domain Wall Properties in 50:50 NiCo Films	W. Carter	5/5/65
136	Ultra Sonic Bonding of Kovar Preform to the Aluminum Pads on a Silicon Die	B. Frescura	4/30/65
137	Thin Film Microinductors	H. Reugg	4/30/65
138	Report on Application of Integrated Circuits (Function Blocks) to ADC and DAC System	R. Palata	4/30/65
139	Further Experiments on the AC Stability of $CT_{\mu}L$ and/or Gates	L. Vadasz	5/5/65
140	Report on the New Technique of Integrating FET and Transistors	J. So	3/26/6
141	Effect of Gold in MOST	J. So	3/24/6
142	Lifetime Control on Laternal pnp Transistors	J. So	3/24/6
143	V,acuum Deposited Silica/Aluminum Films	R. Waits	5/26/6
144	On Masking Against Aluminum Outdiffusion	G. Daughters	6/7/65
145	Composition of Hysol Epoxy Resin System	R. Olberg	6/18/6
146	Composition of a New Hysol Epoxy Formulation H-586 Resin + H-778 Hardener	R. Olberg	6/18/6
147	The Breakdown Voltage of Step p-n Junctions with Arbitrary Acceptor and Donor Levels	O. Leistiko	7/6/65
148	Diode Lead Failures from G.E. Life Test	E. Duffek	7/9/65
149	Calculation of the Profile of a Tapered Film Element and the Demagnetizing Field	W. Carter	7/19/6

TECHNICAL MEMORANDUMS		consent from Director's Office.	
NO.	TITLE	AUTHOR	DATE
150	A Revised Procedure for Drying and Developing KFTR	A. Engvall	7/22/65
151	Kodak Ortho Resist Developer	K. Lemons	7/29/65
152	Composite Photoresist Patterns	G. Daughters	8/10/65
153	Printed Circuit Board Drill Template	E. Armstrong	8/10/65
154	Linear Thermal Expansion of Silicon (Doped and Undoped)	I. Blech	8/12/65
155	Boron Pits and Insoluble Skin Formed During Predeposition	J. Lawrence	8/24/65
156	Measurement of Floor Vibration	B. Yurash	8/25/65
157	Sodium Content of Evaporated Aluminum Films	K. Lemons A. Lewis	9/7/65
158	Chemical Deflashing of Epoxy Encapsulated Diode Modules	R. Olberg	9/7/65
(159)	Tin Plating of the Dual In-Line Package	E. Duffek	9/15/65
160	Equidensitometry, a Useful Photographic Technique for Two Dimensional Image Evaluation	H. Koehler R. Warncke	9/27/65
. 161	Orientation of Crystals for Wafer Slicing	E. Meieran	9/29/65
162	High Output Voltage Amplifier	H. Murphy	9/27/65
163	Structural Damage Induced by Lead Attachment	D. Hilbiber	10/4/65
164	Gold Ball Bonding to Narrow (<0.4 mil) Aluminum Stripes	D. Myers	10/5/65
165	Analysis of Diborane of Phosphine in Hydrogen	B. Yurash	10/8/65
166	Determination of Pinholes and Thin Areas in Gold Plated Over Kovar	K. Lemons	10/8/65
167	An Improved Dual Emitter Chopper (0008)	J. So	8/23/65
168	A Summary of PL/I	G. Chesley	10/11/65
169	Dependence of Photoresponsivity on Carrier Lifetime	R. Dyck	10/13/65

FAIRCHILD R&D

0

FAIRCHI	LD R&D	COMPANY PRIVATE – reproduced or disclos employees without exp consent from Directors	ed to non- press written
NO.	TITLE	AUTHOR	DATE
*170	Epoxy Encapsulant for Microdiode: Composition of Present System and Recommendations	R. Olberg	10/15/65
171	Summary of a Simplified Non-Planar Process for GaAs Hot Electron Diode	A. Hardin	10/6/65
172	Experimental Photoelectric Block Paper Tape Reader	H. Murphy	10/27/65
173	Injection of Minority Carriers at a Field-Induced Junction Near the Si-SiO ₂ Interface	G. Reddi	11/5/65
174	"Creep" of Junction Breakdown Voltages	D. Fitzgerald A. Grove	11/4/65
175	Autopsy of a TO-200 Channel Current Reject	D. Fitzgerald A. Grove	11/4/65
176	Diode Lead Failures from Salt Spray Testing	E. Duffek	11/5/65
177	Solder Masking Tape	P. Ullman	11/9/65
178	Evaluation of Electron-Beam Metallization, HF Dip Prior to Metallization, and Hot H_2^0 Spray Prior to Final Seal in Regard to T1250 Stability During High Reliability Aging	B. Kennedy	11/9/65
179	Some Data on the Effect of Anodic Oxidation on Transistors	J. So	12/6/65
180	Metallic Beads and Lead Problems in Cerpak Production	E. Duffek	1/5/66
181	Detrimental Effect of TCE and Acetone Rinses After Scribing on MOS Device Stability	B. Deal	12/9/65
182	The Uncertainties Associated with the Use of Color Temperature to Specify Tungsten Lamp Emission Spectra for 0.4 μ < λ < 1.2 μ	R. Dyck	12/20/65
183	Scanning Electron Microscope Applications	E. Meieran H. Koehler	12/17/65
184	Characteristics of a Relatively High Voltage MOS Transistor	W. Hooper A. Grove	12/28/65
185	Etching of Vapor Deposited Silica	J. Gordon	12/30/65
186	Air Analysis, Mt. View Plating Shop	B. Yurash	1/22/66

đ

-10-

TECHNICAL MEMORANDUMS		consent from Director's Office.	
NO.	TITLE	AUTHOR	DATE
187	Investigation of Particle Contamination in Laminar Flow Work Stations	J. Noll	1/10/66
188	Particle Counts in Various Locations of the R&D Laboratory	J. Noll	1/12/66
189	An Emitter Diffusion Process Employing Anodic Oxide for Microwave Devices	D. Pilling	2/16/66
190	Removal of Nichrome During Aluminum Etching	L. Danley	1/12/66
191	Cancelled		
192	Review of All Row-and-Column Alignment Marks on Existing Masks	S. Fok R. Ivancich	2/24/66
193	Origin of the Electrical Resistance in the Al/Ni Bump Plating System	I. Blech	2/16/66
194	Air Analysis (During Glass Melt Preparation) Furnace Room No. 6, R&D Basement	B. Yurash	2/16/66
195	Evaluation of Solvents used for Cleaning MOS Capacitors	B. Deal	1/19/66
196	DI Water Quality Improvement	B. Yurash	1/31/66
197	Electrostatic Printing Application of Sealant Glass for the DIP	K. Kanazawa R. Gunnison	2/4/66
198	FPB Light Pulser Plating Procedures	E. Armstrong	2/18/66
199	Effect of Methyl and Ethyl Alcohols on MOS Stability	B. Deal	2/8/66
200	An Improved p-n Junction Staining Technique	J. Lawrence W. Wandry	2/16/66
201	Mechanical Strength of Ultrasonically Bonded 1 Mill Al Wires on the IBM Package	I. Blech	2/16/66
202	FLATPAK Ceramic Header - Final Seal Hermeticity	E. Kanazawa	2/23/66
203	IBM Packages - Metallization, Hermeticity, Metallic Beads and Plating Problems	E. Duffek	2/24/66
204	Composition of Delta Bond 152 Thermal Conductive Adhesive (Wakefield Engineering)	R. Olberg	2/23/66

FAIRCHILD R&D

FAIRCHILD R&D

TECHNICAL MEMORANDUMS AUTHOR DATE NO. TITLE 205 Further Evaluation of the Effect of B. Deal 2/24/66 Isopropyl Alcohol Vapor on MOS Device Stability G. Reddi 3/2/66 206 Design of Transistors for Optimum Low Current h_{FE} 207 Cancelled. E. Kanazawa 3/18/66 208 Gold-Platinum Metallizing for Alumina -An Evaluation of Solder Joint Strength W. Steffe 3/23/66 209 Thermal Tests of Delta Bond 152 Thermal Conductive Adhesive (Wakefield Engineering) E. Duffek 3/28/66 210 The Post Plated Cerpak Package--Evaluation of Gold Plating, Salt Atmosphere Resistance and Solderability Tests S. Fok Antireflective Mask Status Review 3/29/66 *211) D. Bradbury 3/23/66 Fine Line Conductive Patterns for "Flip 212 Chip" Packaging A. Davis 4/4/66 213 Preliminary Study of Silica Deposition in a Tube Reactor from the Silane-Oxygen Reaction W. Shepherd 4/1/66 214 Silicon Thickness Uniformity in Production Epitaxial Reactors-Influence of Plate Width D. Fitzgerald 4/6/66 215 A Three-Thermal MOX Varactor A. Grove E. Snow 4/6/66 Preliminary Evaluation of Silicon Nitride 216 W. Shepherd Films R. Waits 4/7/66 217 Silicon Dioxide-Magnesium Dioxide-Chromium Resistive Films W. Lehrer 4/7/66 *218 A Lifting Technique to Prepare Ultra-Miniature Contact Geometries E. Wilder 4/6/66 219 The Adverse Effects of Source Biasing MOS Transistors J. Lawrence 4/8/66 220 Effective Life of Metal Removing Solutions R. Borawski 3/22/66 221 0057 - "N" Channel Depletion Mode MOST PNP Radiation Resistant Transistor Selection G. Steres 4/19/66 222

222 Addendum

TECHN	CAL MEMORANDUMS	consent from Director's O	пісе.
<u>NO</u> .	TITLE	AUTHOR	DATE
223	Delta Bond 152 - Mechanical Strength Evaluation	E. Kanazawa	4/20/66
224	New DIE Attach Preform	P. Ullman	4/27/66
225	Process for Tin-Nickel Alloy Plating TO-3 Headers	E. Duffek	8/16/66
226	The Use of Differential Thermal Analysis for Quality Control and Development Work on Solder Glasses	J. Longwell	4/28/66
227	Copper-Nickel Plating TO-5 Headers	E. Duffek	5/10/66
228	Special Problems and a Comparison of the TO-301 and TO-304	R. Whittier	5/24/66
229	Results of EB Drift Tests on Thermal Oxides for Period 12/65 Through 5/66	B. Deal	5/13/66
230	Tantalum Filament Evaporation of Aluminum and Its Effect on Stability of MOS Structures	B. Deal	5/20/66
231	Preliminary Measurements of Surface Recombination Velocity s _o	D. Fitzgerald A. Grove	5/24/66
232	Gettering, Photosensitivity, and Minority Carrier Lifetime of Silicon Planar Photodiodes	G. Weckler	5/24/66
233	Multiple Gettering	G. Weckler	5/25/66
234	Multiple Gettering of Au Doped Photodevices	G. Weckler	5/26/66
235	Exposures in an Oxygen Free Atmosphere	W. Crevier	6/1/66
236	The CFD Package	E. Kanazawa	6/9/66
237	The Relation Between Drive Currents and Outputs for a Magnetic Thin Film Memory	W. Carter	6/9/66
238	Film Formation on GaAs	E. Meieran D. Mattern	6/13/66
239	Comments on the Nichrome Process 50-300 0/	K. Gohring	6/24/66
240	Fine Line Patterns on Metallized Ceramics- Collins Radio Substrates	E. Armstrong	6/10/66

FAIRCHILD R&D

TECHNIC	CAL MEMORANDUMS		
NO.	TITLE	AUTHOR	DATE
241	Report on Alloy Zener Diodes	R. Hurlston	6/17/66
242	Composition of Eccobond Solder 57C	R. Olberg	6/16/66
243	"Drip-Free" Liquid Filtering Dispenser	E. Blome	6/21/66
244	Aluminum Evaporation from Tantalum Filaments	K. Gohring	7/1/66
245	Stability of Fairchild FL 100 (0028) MOS Transistors	B. Deal	7/8/66
246	Pattern Obscuring During Epitaxy	R. Tucker	7/20/66
247	Ten Kilohm/Square Sputtered Tantalum Resistors	R. Martin	7/12/66
248	An Overhead, Force-Cooled Vacuum Deposition Jig	D. DeFevere	8/13/66
249	Discoloration on Autonetics TO-50 Packages	E. Duffek	7/5/66
250	Electroformed VHF Emitter Ground Seal	E. Armstrong	7/14/66
251	Method for Stripping Epoxy from Devices	R. Olberg	7/12/66
*252	Preliminary KFTR Lift-Off Process for 1 μ Aluminum on SiO ₂ - Al ₂ O ₃ Dielectric	A. Engvall	7/13/66
253	Noise in Read Diode and Gunn Oscillators	H. Ruegg R. Henschke E. Solomon	7/20/66
254	Photoresist Coating Thickness on Silicon Slices	D. Davis 🦂	8/1/66
255	Radiation-Induced Increase in Surface Recombination Velocity of Thermally Oxidized Silicon Structures	A. Grove D. Fitzgerald	7/26/66
256	Palladium and Platinum Lead Bonding Test	P. Ullman	7/28/66
257	Exposures with a Sun Gun Light Source on the Mt. View Semiautomatic Alignment Jig	E. Flath	7/27/66
258	Air Analysis During Cleaning of Furnace Used for Metallizing Beryllium Oxide Ceramic Package Components	B. Yurash	8/ 8/66

FAIRCHILD R&D

Ċ

0

C

COMPANY PRIVATE - Not to be reproduced or disclosed to nonemployees without express written consent from Director's Office.

TECHNICAL MEMORANDUMS		consent from Director's Office.	
<u>NO</u> .	TITLE	AUTHOR	DATE
259	Preferred R&D Laboratory Procedure for Measuring the Absolute Responsivity of Photodiodes and Phototransistors to an Accuracy of About ±3%	R. Dyck	8/10/66
260	Printed Circuit Board Etch Characteristics	É. Duffek E. Armstrong	9/7/66
261	Investigation of MOS Evaluation Procedures for the Aluminum EB Evaporator	J. Kelley	8/18/66
262	X-ray Topographs of GaAs Wafers	E. Meieran	8/16/66
263	Residues on General Precision Diode Leads	E. Duffek	9/20/66
264	Use of Beryllium Metal on Silicon Devices as a Possible Replacement of Aluminum: A Literature Survey	A. Lewis	9/20/66
265	Effects of Fast Neutron Radiation on TO-502 2 Amp h _{FE}	L. Danley	9/22/66
266	Special Problems in Fabrication of TO-502 VHF Power Transistors	L. Danley	8/20/66
267	Special Problems of the DTuL 9969	B. Frescura	9/27/66
268	The Etching of Gallium Arsenide in Bromine/Methanol	W. Lehrer	10/5/66
269	Reflection X-ray Topograph of GaAs Deposited on Ge	E. Meieran	9/30/66
270	Drift Experiments on RCA MOS Capacitors	D. Fitzgerald A. Grove	10/20/66
271	Special Problems in Fabrication of TO 115- npn 20V LV _{CEO} Radiation Tolerant General- Purpose Amplifier	D. Myers	10/14/66
272	Preliminary Evaluation of Illumination	E. Blome S. Fok	10/17/66
273	Photoresist and Etch Systems for SiO ₂ -Al ₂ O ₃ and 7059 Glass Dielectric Films	A. Engvall	10/18/66
274	Evaluation of Prototype R&D Resist Dispenser	T. Menzies	10/18/66

TECHNIC	AL MEMORANDUMS	consent from Directo	rs once.
NO.	TITLE	AUTHOR	DATE
275	Some Qualitative Aspects of Electrotrans- port Let Failure	H. Kroemer	11/3/66
276	Pattern Plating Flip-Chip Ceramic Substrates	E. Duffek	10/18/66
277	Status of Scanning Electron Microscopy	E. Meieran	11/7/66
278	Cause of Glass Breakage in Molded Diode Arrays	R. Harline	11/11/66
279	Removal of Photoresist from Metal & Oxide Surfaces	C. Gunter P. Portesi	11/15/66
280	Emitter-Base Junction Degradation in the P-1000 Phototransistor During Power Lifetest	R. Dyck	11/23/66
281	Evaluation of GI "Herculeads" Beam Lead Diodes	I. Blech	11/29/66
282	Structure of Sputtered Thin Ta Films	E. Meieran	12/13/66
283	Life Test Comparison of Metal Can Packages with Standard Epoxy H586 Encapsulation for Three Fairchild Devices (1250, 4204, 0054)	M. Dumesnil	12/6/66
284	Rapid Separation of Marked Bad Dice	R. Olberg	12/6/66
*285	Silicon Monoxide Films as Transparent Working Plates	W. Lehrer	12/9/66
286	Single Position Spin Coater	C. Gunter W. Hokeness	12/9/66
287	Design and Development of the 0058	J. Archer	12/20/66
288	Properties and Microstructural Character- istics of Beryllium Oxide-Part I	M. Mendelson	12/19/66
289	Improved Dicing Yields	E. Meieran	12/13/66
290	CATV Systems	B. Jones	12/20/66
*291	Hard Surface Mask Output(s) on a Rapid Turn Around Basis	E. Blome	1/26/67
292	Pico-Amp Diode Package Evaluation	R. Hurlston	1/27/67
293	Heat Treatments to Lower Aluminum to Aluminum Interface Resistance	G. McNeil	1/23/67

FAIRCHILD R&D

consent from Director's Of	flice.
AUTHOR	DATE
G. McNeil	1/23/67
B. Deal	1/24/67
B. Jones	1/25/67
D. Henderson	1/24/67
E. Armstrong	1/25/67
D. Frohman/ Bentchkowsky L. Vadasz	1/26/67
D. Forbes	1/30/67
B. Yurash	1/7/67
B. Yurash	2/9/67
B. Deal	2/10/67
H. Koremer s" R. Rao R. Solomon	2/17/67
B. Kennedy	3/3/67
W. Phy	2/16/67
M. Mendelson	2/21/67
D. Myers	3/3/67
E. Wilder L. Vadasz	2/17/67
J. Muschinske	3/10/67
E. Blome	3/8/67
	AUTHOR G. McNeil B. Deal B. Jones D. Henderson E. Armstrong D. Frohman/ Bentchkowsky L. Vadasz D. Forbes B. Yurash B. Yurash B. Yurash B. Yurash B. Deal H. Koremer R. Rao R. Solomon B. Kennedy W. Phy M. Mendelson D. Myers E. Wilder L. Vadasz J. Muschinske

0

O

3

FAIRCHILD R&D

TECHNI	CAL MEMORANDUMS	consent from Director's (Uffice.
NO.	TITLE	AUTHOR	DATE
312	Lapping and Backlapping Process Change and Standardization	D. McCall	3/1/67
*313	KFTR Life-Off of 1 μ Aluminum	G. McNeil	4/17/67
314	Factors Determining SCR and TRIAC Die Size and Cost	W. Kauffman	3/27/67
315	Application of Ultrasonic Bonding with Aluminum Wire to the Epoxy Package	R. Olberg	9/14/67
316	Stained Leads: Electro-Mex, Tijuana	E. Duffek	9/8/67
317	The Determination of Concentration Profiles by Anodic Profiling	D. Henderson	4/21/67
318	The Removal of Surface Debris from Mounted Dice	J. Lawrence	3/21/67
319	Conductive Epoxy and Silver Migration	L. J. Kabell	3/27/67
*320	Comparison of Castorex 11-2 (R&D Epoxy) vs Hysol 586	R. Olberg	3/17/67
321	High Pressure Mercury Arc Lamp Exposure Light Variations	E. Blome	3/31/67
*322	Trip Report, Visit to Bell Telephone Laboratories, Allentown, Pa, and Murray Hill, NJ	C. Bittmann I. Blech R. Tucker	4/5/67
323	Special Problems of the TO-303	J. LeGall	4/10/67
324	Special Problems of TO-306	F. C. Jones	4/10/67
325	Spike Defects on Epitaxial Si Wafers	E. Meieran	4/2/67
326	Results of Microprobe Analysis of Glass Masks	E. Meieran	3/6/67
327	Special Problems of D9100	J. Schroeder	4/30/67
328	Status Report on High Voltage Mesa Rectifiers	R. Hurlston	4/13/67
329	Power Transistors with Discrete Nichrome Resistors - Control of Resistor Value and Burnout Current	J. Muschinske	4/17/67

330 Cancelled

FAIRCHILD R&D

	TITLE	AUTHOR	DATE
<u>NO</u> . 331	Diode Leads - Solder Dipping and	E. Duffek	6/28/67
332	Solderability Problems Terminology Associated with MOS Surface Charge Measurements and Related Processing	P. Castro M. Sklar B. Deal	5/9/67
333	Scratch Resistant Protective Glass on Fairchild Light Pulser Arrays	W. Lafky	5/12/67
*334	Evaluation of a Transparent Silicon Monoxide Film Process for use with Visually Transparent Masks	E. Blome	5/10/67
*335	Evaluation of SGS Epoxy Resin Systems	R. Olberg	5/18/67
336	Boron Pin-Hole Diffusions in Integrated Circuits	J. Lawrence	6/2/67
	Thick Film Production Line	M. Dumesnil	6/2/67
337 338	Preliminary Evaluation of Gallium Arsenide MOS Field Effect Transistors	C. Bittmann	6/5/67
339	Sodium Content of Materials used in Device Processing	B. Yurash	6/7/67
340	Evaluation of Lens for Projection Printing Leitz Canada, COODO3 UNELCAN C91, f/4.5 72 mm	C. Van Ness	6/6/67
* 341	Sputtered Silicide Resistor Status	R. Waits	6/8/67
342	Addendum to Technical Memorandum #239 "Comments on the Ni-Cr Process"	K. Gohring	6/19/67
343	TO-803 Transfer Memo	W. Kauffman	6/19/67
343	Combination Metal of Bimetal Evaporation Masks	M. Focht	6/20/67
345	The Cause and Prevention of Star Defects in Integrated Circuits	J. Lawrence	6/22/67
346	Report on Visits to European Laboratories	H. Kroemer	7/12/67
340	New Film Element Analysis	F. Greene	7/6/67
348	Procedure for Cleaning Headers Rejected for Electrical Leakage	J. Lawrence	7/25/67

FAIRCHILD R&D

O

FAIRCHILD R&D

0

0

TECHNI	CAL MEMORANDUMS		
NO.	TITLE	AUTHOR	DATE
349	Boron Predeposition-Wafer Storage Defects	J. Lawrence	7/14/67
350	Current Density Limits of Thick Aluminum Stripes in the FLA-610 and FLA-630	R. Dyck W. Lafky	8/4/67
351	Evaluation of Mt. View FT-0057 MOST	R. Hurlston	7/25/67
352	Cancelled		
353	SAM Stack Design Report	J. Friedrich	8/25/67
354	Some Causes of Inadequate Gold Alloying	J. Lawrence	8/23/67
355	h _{FE} Degradation Resulting from Emitter-Base Junction Avalanching	D. Fitzgerald	8/28/67
356	72-Bit Memory Array Fabricated with Redundant Rows of Cells for Yield Enhancement	J. Angell	9/7/67
357	On Dislocations in Silicon Semiconductor Devices	J. Lawrence	11/20/6
358	Dust Counts, R&D and Military Products Assembly Areas	B. Yurash	10/17/6
359	Sodium Content of Barnstead Cascade Wash System	B. Yurash	10/17/6
360	Contamination During Wafer Drying	P. Portesi	10/25/6
361	Competitive Gallium Arsenide Infrared Light Emitter Diode - RCA TA-7008	M. Khambaty	10/25/6
362	Technique for Achieving Uniform Aluminum Etching	R. Dorilag G. McNiel	10/23/6
363	Photoresist Removal by Low Temperature Ashing Using Electrically Excited Oxygen	D. Davis B. Yurash	10/18/6
364	Shift of C-V Characteristic in MOS Capacitors - More Data on Time Temperature Dependence	B. Raney	10/20/6
365	LIC Component Optimization, µA725 Kit Part Evaluation	B. Kennedy	11/9/67
366	Evaluation of TO-18 Plastic Header	R. Olberg	11/9/6
367	The Effects of the Graded EB Diode on Base Transit Time	D. Duncan	11/27/

2.

0

0

COMPANY PRIVATE -- Not to be reproduced or disclosed to nonemployees without express written consent from Director's Office.

TECHNI	CAL MEMORANDUMS		
NO.	TITLE	AUTHOR	DATE
368	Etching Fairpak Substrates with AZ 345 Photoresist	E. Duffek	11/20/67
369	Evaluation K+S 688 Telefunken-Zeiss Projection Mask Alignment System	G. McNiel F. Rosengarten	12/5/67
370	Lifetime Measurements in Epitaxial Layers	W. Kohler	12/8/67
371	Cracking in Silicon Nitride Films	W. Kohler	12/29/67
372	Stained Posts: Electro-Mex, Tijuana	E. Duffek	11/29/67
373	Wrinkled Aluminum Caused by Copper Contamination	R. Waits	12/8/67
374	Base Transit Time for Inverted Mode Operation of Bipolar Transistors	D. Duncan	12/13/67
375	Minimizing Aluminum to Silicon Contact Resistance	G. McNiel	12/13/67
376	Electrochemical Society Meeting Chicago, Illinois - October 15-20, 1967	H. Sello	1/12/68
377	Contact Spring Pressure and Reliability Test	W. Willis	12/13/67
378	Pyrolytic Deposition of Silicon Nitride in a Flokol Reactor	W. Kohler J. Flood	12/28/67
379	Specific Resistance, Particle and Bacteria Colony Counts and Sodium Content of Deionized Water at R&D	R. Kouyoumdjian F. Grasso	1/1/68
*380	TO-109 Development	J. Archer	1/17/68
*381	Hermeticity of Epoxy Sealed Ceramic Packages	R. Olberg	1/1/68
382	Improvement of Diode Array Glassing Process	R. Rusert	12/28/67
383	Synthesis of Arsenious Chloride	R. Kouyoumdjian	1/15/68
*384	The Etching of Silicon Nitride in Phosphoric Acid with Silane Primes Photoresist as a Mask	A. Engvall	1/17/68
385	Evaluation of Device Development Silicon NitrideHot Tube and RF Systems	B. Deal	1/17/68

TECHNIC	AL MEMORANDUMS		
NO.	TITLE	AUTHOR	DATE
386	Possibility for the Determination of Sodium Content of Water Derived from the Condensation of Water Vapor from Oxidation Furnaces by Measurements of Specific Resistance	R. Kouyoumdjian B. Yurash	1/30/68
387	Wafer Etching and Inspection for Epitaxial Growth	W. Kohler	2/8/68
388	Conduction and Switching Mechanism in Glass	M. Dumesnil	2/5/68
389	β Test for High Gain Bipolar Transistors	R. Whittier R. Jenkins	8/23/68
*390	 Low Q vs High Q Emitter Processing of npn Transistors II. Processing Effects on npn Transistor Noise 	P. Downing R. Whittier	2/29/68
391	Cancelled		
392	Maximizing the Gain Bandwidth Product of RC Coupled IC MOS Tetrodes	R. Lane	2/29/68
393	DIED 6 Head Spinner	G. McNiel	3/4/68
394	Developments in Fine-Line Patterning on Metallized Ceramics Processing of the CPE-1003 Substrate	E. Duffek M. Focht	3/4/68
395	Design of Low Noise Transistors	R. Whittier	3/11/68
396	Definition of Diode Array "Zapping" Problem	R. Rusert	3/12/68
397	Dielectric Strength of Insulators on Silicon	B. Deal	3/19/68
398	Stress Performance of #10 Glassed npn 1250	M. Dumesnil	4/2/68
399	Preliminary Evaluation of Aluminum- Silicon Schottky Barrier Diodes	A. Yu E. Snow P. Downing	3/22/68
400	Temperature & Humidity Resistance of Typical Photo-Sensing Array Packages Sealed with Film Epoxy (Enviroseal)	B. Phy	3/18/68
401	Vapox Passivation by Means of Phosphorus Glass	C. Steele D. Frohman/ Bentchkowsky	3/25/68
		Bentchkowsky	

.

1

O

0

FAIRCHILD R&D

FAI	RCHI	LD	R&D

C

.

TECHNICAL MEMORANDUMS

TECHNICAL MEMORANDUMS			nom piectors office.	
NO.	TITLE	AUTHOR	DATE	
402	Cause and Prevention of Soft Junctions in Integrated Circuits	J. Lawrence	3/21/68	
403	Feasibility Studies of Si-Gated MOS Structures	T. Klein	3/25/68	
404	Post Masking and Pre-Diffusion Wafer Cleaning	G. McNiel F. Hall	3/29/68	
405	Improvement of Air Isolation Glassing Process	R. Rusert	4/29/68	
406	Characterization of 2 kΩ/□ Silicon Chromium Resistors	D. Oberlin K. Stafford	3/3/68	
407	Distillation of Arsenious Chloride (Part I)	R. Kouyoumdjian	4/8/68	
408	4500-29 Test Array Analysis	J. Campbell R. Carlstead	4/8/68	
409	Variation of Drift VI and Phosphorus Glass Polarization with Alloying Temperature	C. Steele	5/10/68	
410	A Delineating Technique for Stain Films on Aluminum Pads	J. Lawrence	5/7/68	
411	Correlation Between MOS Transistor and C-V Measurements	D. Frohman/ Bentchkowsky	5/17/68	
412	Properties of Mo-Mn Metallization on Alumina - Initial Investigation	M. Mendelson	5/14/68	
413	On the Theory and Measurement of Base Current Due to Recombination of Excess Carriers in the Neutral Base	J. Downing R. Whittier	5/15/68	
414	Stabilizing Bipolar Arrays with Silicon Nitride	D. Pilling	5/21/68	
415	Comparison of Magnetics and Semiconductor Memory Systems	C. Bittmann	5/24/68	
416	Test Structure for the Study of Package Related Failure Mechanisms	E. Snow	5/29/68	
417	Electrochemical Society Meeting Boston, Massachusetts - May 5-9, 1968	B. Deal L. Bernstein B. Cairns E. MacKenna	6/4/68	

	HILD R&D ICAL MEMORANDUMS	employees without express written consent from Director's Office.	
NO.	TITLE	AUTHOR	DATE
418	Quality Control of Anhydrides Used in Epoxy Cure	B. Yurash R. Ceynowa	6/4/68
419	Low Defect Masking Processes	A. Mills	6/12/68
420	Encapsulation of FPT-100 Phototransistors with Nupol Thermosetting Acrylic	W. Phy	6/21/68
421	Thermal Resistance of Beam Leaded Devices on Dual In-Line Packages	M. Mendelson	6/18/68
422	Stress Cracking Failure of Polypropylene Waste Piping	B. Yurash	7/8/68
423	Oxidation Rates Applicable to Bipolar Circuit Processing	J. Podell	7/26/68
424	Fairchild Memory Study (Magnetic Films on Silicon) *Iowa State Univ. EE Dept.	A. V. Pohm* C. A. Bittmann	7/31/68
425	Evaluation of Kodak Photoresist MX-741 (A Clarified KMER)	A. Mills	8/5/68
426	Silane Priming for the Prevention of KMER and DTFR Lifting in Production	A. Engvall	8/19/68
427	Evaluation of Diamond Band Saw	W. Phy	8/9/68
428	Phosphorus Penetration into Silicon Dioxide from a POCl ₃ Source	J. Podell F. Rosengarten	8/15/68
429	Sputtered Si-Cr Resistive Films	R. Waits	8/15/68
430	A New Technique for Delineating Sputtered Mo-Si 200 Ω/□ Thin Film Resistors	W. Khadder J. Weber	8/12/68
431	Saturation Resistance and Current Gain as a Function of Collector Geometry of a CML Transistor	P. Doshi	8/23/68
432	X-Ray Topographs of GaAs Wafers	E. Meieran	9/5/68
433	Anisotropic Etching of Silicon	R. Rusert	8/23/68
434	Cancelled		
435	Effective Boron J D with One Hour	F. Rosengarten D. Peltzer	9/11/6

(;)

C

5

Oxidations

-24-

	CAL MEMORANDUMS	AUTHOR	DATE
NO.	TITLE		
436	Solvent Resistance of Acrylic Encapsulated FPT-100 Phototransistors	W. Phy	9/18/68
437	Note on the Polishing of Solution Grown GaAs Epitaxial Layers	R. Solomon	9/13/68
438	Particles from Thread LubricantAn Alert!	H. Sello	9/11/68
439	Evaluation of Stripping Agents for Plastic Packages	R. Olberg	9/13/68
440	Autonetics FPT Package: Moisture Resis- tance Failures	E. Duffek	9/11/68
441	Notes on the Process for Etching Silicon Nitride	A. Engvall	9/23/68
442	Performance of GaAs Bulk Effect Oscillators	M. Shyam	9/3/68
443	Avalanche Degradation of h _{FE}	B. McDonald	10/31/6
444	Failure Analysis of D9100 Diode Array	R. Rusert	10/4/68
445	Evaluation of 250 mm Ultra-Micro-Nikkor f/1.0 1:1 Lens (Serial #102302) for Projection Printing	S. Fok J. Winding	10/25/6
446	A Comparison of Non-Epitaxial Deposited Si Films	E. Meieran	11/4/68
447	Sputtered Silicon-Chromium Resistor Films on Silicon Oxide and Silicon Nitride Surfaces	P. Fehlhaber	11/15/6
448	Sodium Content of Materials: Addendum #1	B. Ceynowa	11/14/6
449	Very Low Power Circuits	S. Townsend	11/19/6
450	Aluminum-Silicon Schottky Barrier Diode Life Test	A. Yu	11/19/0
451	Electrochemical Society Meeting Montreal, Canada - October 6-11, 1968	B. Deal	11/19/
452	Epoxy Die-Down for Hybrids - A Final Summary	S. Cagnina	11/22/
453	Integrated Circuit High Ohms/Square Diffused Resistors	J. Podell	12/9/6

FAIRCHILD R&D

0

TECHNICAL MEMODANDUMS

•

0

0

COMPANY PRIVATE – Not to be reproduced or disclosed to nonemployees without express written consent from Director's Office.

NO.	TITLE	AUTHOR	DATE
454	Epitaxial Growth on (100) and (111) Substrates	T. Swanson E. Yim	12/2/68
455	The Measurement of Contact Resistance	D. Duncan	12/10/68
456	Evaluation of Commercial Molding Powders	R. Olberg D. Harline	12/4/68
457	FAE Package: Moisture Resistance Failure II. Base Header Corrosion and Glass Cracking	E. Duffek	1/17/69
458	The New 1/10X Micro-Tropar Lens	S. Fok J. Winding	12/12/68
459	Effect of Post-Vacuum Impregnation of Molded Dips on Moisture Penetration	R. Olberg D. Harline	12/18/68
460	Calculation of High Frequency Available Gain and Noise Figure of Bipolar Devices	M. Purnaiya	12/20/68
461	TO-122 npn Transistor	D. Duncan	1/69
462	Degree of Cure of Castorez 11-2 Epoxy as a Function of Time and Temperature	R. Olberg	1/20/69
463	Comparison of Gold-Doped Transistors	R. Aldrich R. Foglesong	5/21/69
464	The Effect of Emitter Area on V_{BE} and TC of V_{BE} Matching for npn Transistor Pairs	D. Oberlin	1/28/69
465	The Hitachi npn 2SC458. An Analysis	M. Dumesnil W. Kauffman B. Jones	2/16/69
466	Uniformity of Photoresponse of Linear Diode Arrays	W. Lafky	1/30/69
467	Report on the Atlanta Workshop on GaAs Microwave Oscillators, January 28-29, 1969	M. Shyam	2/17/69
468	Cancelled		
469	Gold Etch Back Technology for Producing Multichip Substrates	E. Stefanowicz	3/14/69
470	Contaminants in Epoxy Resin	R. Olberg	3/3/69

FAIRCHILD R&D

C

TECHNICAL MEMORANDUMS			
NO.	TITLE	AUTHOR	DATE
471	Comparison of the Applied Materials Technology "Silox" Process and the Fairchild Phosphovapox Process	M. Barry	3/11/69
472	Vapor Phase Etching of Silicon Oxides	A. Engvall	3/19/69
473	Projection Printing with the Model #1 Projection Alignment Jig	A. Engvall	3/25/69
474	Report on Visits to SPSE Seminar, HLC Eng. Co., and Jade Corp., March 6 & 7, 1969	S. Fok	3/26/69
475	Simple Empirical Method for Estimating Thermal Resistance Component of Ceramic Substrate	S. Cagnina	3/28/69
476	Properties of Silicon Nitride Films	V. Rodriguez	4/11/69
477	Evaluation of Applied Materials Technology Phosphovapox Films	B. Deal M. Sklar E. MacKenna	4/14/69
478	Some Special Designs of Hot-Electron Diodes (HEDs)	A. Yu	4/16/69
479	APS March 1969 Meeting	A. Yu	4/22/69
480	Realloy of Aluminum Contacts to Bipolar Transistors	P. Downing	4/14/69
481	Evaluation of "Isodiode" of Isofilm International	A. Yu	4/17/69
482	Optimization of Aluminum Deposition Thickness and Uniformity in Fairchild "Sputter Clean" Vacuum Systems	L. Fritz	3/20/69
483	Detection and Prevention of Carbon Impurities in Silicon Dioxide Prior to Silicon Nitride Growth	W. Kohler	5/7/69
484	Re-evaluation of the R&D Copy Camera Preliminary Test Results	S. Fok J. Winding	6/4/69
485	Ineffectiveness of Aluminum as a Sodium Barrier	B. McDonald	5/26/69
486	Electrochemical Society Meeting New York: May 4-9, 1969	B. Deal	6/12/6

FAIRCHILD R&D

C

C

TECHNI	CAL MEMORANDUMS		
NO.	TITLE	AUTHOR	DATE
487	Increasing the Efficiency and Decreasing the Overall Cost of Using X-ray Orientation and Radiography at Fairchild Semiconductor	E. Meieran	6/18/69
488	Varo Prototype Pattern Generator Evaluation	S. Fok	6/20/69
489	Pyrolytic Silicon Nitride Deposition in a Conveyor Belt Furnace	W. Kohler J. Flood	6/24/69
490	Further Verification of a Model for Diffusion from Doped Oxides	M. Barry J. Manoliu	6/27/69
491	Temperature Measurement in an RF-Heated Reactor	E. MacKenna P. Kodama	6/26/69
492	Junction Gettering with Phosphovapox	M. Barry	7/3/69
493	Direct Plotting of Carrier Concentration Profiles	P. Hower	7/10/6
494	Epoxy Adhesive Sealants for Ceramic Packages	R. Olberg	7/14/6
495	Drift in Aluminum - Silicon Contact Resistance	E. Yim	7/16/6
496	Metal Cracking Observed on MOS Integrated Circuits	D. Forsythe	8/4/69
497	Design of Schottky Barrier Diode pnp Transistor	M. Lenzlinger	7/18/6
498	Bulk GaAs Evaluation	E. Meieran	7/28/6
499	High Gain-Bandwidth Phototransistor	G. Slaten	8/15/6
500	Phosphorus Penetration into Vapox from POC1 ₃ Source	M. Barry	8/13/6
501	The Effect of Heated Substrate Aluminum Evaporation on MOS Stability	M. Sklar	8/26/6
502	Gun Effect Oscillator - Detailed Experi- mental Results	M. Shyam	8/28/6
503	Residual Gases During Filament Evaporations	J. Campbell	10/3/6
504	T-0107 Small Signal, High Gain Transistor	G. Sloan	9/2/69

0

-

COMPANY PRIVATE - Not to be reproduced or disclosed to nonemployees without express written consent from Director's Office.

	ICAL MEMORANDUMS	consent from Director's	s Office.
NO.	TITLE	AUTHOR	DATE
505	Clean Photoresist Techniques	P. Castro	9/10/69
506	Geometrical Shadowing Effects During Deposition of Thin Al Films Over Steps	I. Blech J. Campbell	9/22/69
507	Analysis and Control of Deionized Water Used for Semiconductor Processing	B. Yurash	9/25/69
508	The Measurement of Contact Resistance Using Mask-Set CRTA	D. Duncan	10/10/69
509	A Method to Limit the Spectral Response of Silicon Photosensors to the Visible Range	W. Phy	9/26/69
510	Evaluation of Silicone Junction Coatings	R. Olberg	10/15/69
511	Autopsy and Analysis of Philco LIC Package	R. Olberg W. Wandry	10/15/69
512	Preliminary Evaluation of AMT's Infrared Heated Silicon	E. MacKenna	10/15/69
513	Recent Developments Concerning the Nikon 1:1 Projection and Other Lenses	S. Fok	11/3/69
514	Dependence of Beta on Collector Current for a New Linear Phototransistor Array Design	W. Lafky	10/15/69
515	Dislocations in Si Crystals	E. Meieran	10/15/69
516	Evaluation of Mt. View Clic Si ₃ N ₄ Process	E. MacKenna	11/10/69
517	Leitz 1:1 Lens for Projection Printing	S. Fok J. Winding	11/3/69
518	Stripping Epoxy Encapsulated Devices with Fuming Sulfuric Acid	R. Olberg	11/12/69
519	Controlling Viscosity of Hysol Castorez	R. Olberg	11/14/69
520	"Figure of Merit" for Gate Protection	M. Lenzlinger	11/7/69
521	Current Level Logic or Clamped Mode Logic	D. Duncan	11/28/69
522	Initial Characterization of Collector Diffused Isolation Transistors	G. Spedea	4/20/70
523	Electrochemical Society Meeting Detroit - November 5-10, 1969	M. L. Barry	11/21/69

FAIRCHILD R&D

...

TECHNICAL MEMORANDUMS

NO.	TITLE	AUTHOR	DATE
524	Comparison Between Reflective and Anti- reflective Chrome Mass	D. Courtis	4/1/70
525	Conference at Freeman Chemical Company on Nupol	W. Phy R. Olberg	11/28/69
526	Out-Diffusion from Diffused Phosphorus Layers	C. Steele	12/1/69
527	Noise in MOS Transistors	S. Hsu	12/10/69
528	Fast Surface States Associated with Si-Gate Processing	P. Castro	12/10/69
529	Residual Gas Analysis During Electron Beam Evaporation	J. Campbell	12/15/69
530	Effect of Substrate Orientation on Poly- Si-Isolation Structures	T. Kamins	12/30/69
531	Optimum Base Shaped Design to Minimize Corner Breakdown of Rectangular Planar Diodes	D. Duncan	12/29/69
532	Ineffectiveness of Polycrystalline Silicon as a Sodium Barrier	B. McDonald	12/15/69
533	Updated Silane Priming Recommendation	A. E. Engvall	1/2/70
534	Gunn Effect Oscillator - Studies Using Mesa Structure	M. Shyam	12/30/6
535	An Improved Method of Anodic Sectioning	D. Duncan	12/29/6
536	Properties of Plastic Materials for Optoelectronic Devices	R. Olberg	1/5/70
537	An Extremely Accurate Backlapping Technique - Waxless Backlapping	D. Oberlin	2/25/70
538	Electrochemical Etching for Dielectric Isolation	D. Oberlin J. Michel	3/30/70
539	Investigation into the Effects of the Tracerlab Plasma Photoresist Dry Stripper- 504 on Surface Charges	P. Castro	1/28/70
540	Sodium Masking by Silicon Nitride	V. Rodriguez P. Fleming E. MacKenna	1/26/70

TECHN	IICAL MEMORANDUMS	Consent from Director	s onice.
<u>NO</u> .	TITLE	AUTHOR	DATE
541	Preliminary Evaluation of Silane Epitaxial Layers Grown on SF ₆ -Etched Surfaces	T. Kamins	1/20/70
542	Field Plate Design	P. Froess	1/29/70
543	Evaluation of Filaments for Aluminum Evaporation	M. Sklar	2/2/70
544	Evaluation of Toshiba Silicon Microwave Transistors	J. Archer	2/5/70
545	Report on the 1970 GaAs Microwave Oscil- lator Workshop, St. Louis, Mo.	M. Shyam B. Cairns	2/16/70
546	Trip Report: GaP Technology at Bell Telephone Laboratories	E. Snow R. Solomon J. Raymond R. Zettler	2/20/70
547	Gold Tin Soldered Leads on Packages with all Aluminum Metallizing	E. Stefanowicz	3/19/70
548	Continuous Nitride Process - Some Additional Experiments	W. Kohler	3/25/70
549	Comparison of 680° and 1035°C Poly-Silicon: Electrical Properties	T. Kamins	4/1/70
550	Evaluation of New G.E. Transistor in the TO-92 Package	R. C. Olberg	2/5/70
551	Silicon Nitride Reactors	E. MacKenna	4/13/70
552	A Way to Increase the Field Oxide Threshold on MOS Devices Using a Thin Antimony Layer	D. Cheung	4/1/70
553	Silicon Stains on MSI Devices	E. W. Yim	4/10/70
554	Improvement of Gold-Aluminum Thermo- compression Bonds	R. Hansen W. Wandry	4/8/70
555	Frequency Effects in Polycrystalline Silicon	T. Kamins J. Manoliu	4/24/70
556	Chip Protection: High Humidity Reliability Study of a Silicon Nitride Passivated npn Device (TFC 0100) in Epoxy Plastic Packaging	M. Dumesnil	6/5/70

#

С

FAIRCHILD R&D

FAIRCHILD R&D

> TECHNICAL MEMORANDUMS NO. AUTHOR DATE TITLE 557 M. Sklar 5/14/70 Preparation of Standard Thermox M. Sklar 558 Preparation of Standard MOS Capacitors 5/14/70 M. Sklar 5/14/70 559 Minimization of Q Due to Aluminum D. McCall Evaporation M. Sklar 5/14/70 560 MOS Capacitance-Voltage Measurement 5/20/70 E. Meieran 561 Orientation of Si Wafers for Maximum Scribing Yields F. Rosengarten 5/20/70 562 Evaluation of the Headway Photoresist Spinner, Model AHT3 W. Shepherd 5/26/70 Some Correlations Between MSIA Test Data 563 and 4100 Circuit Parameters J. Shea 5/12/70 564 **TFCA 101 Progress Report** B. Yurash 6/2/70 565 Chemical Analysis by Atomic Absorption Spectroscopy, Requirements and Limitations 5/29/70 R. Olberg Evaluation of Amaplast Red 2Y Dye Filters 566 E. Martich in Nupol and Castorez 96-1 Plastic Lens 7/1/70 I. A. Blech Evaporated Film Profiles Over Steps in Sub-567 strates W. Kohler 6/22/70 Silicon Nitride Deposition in the pnp 568 Flokol Production Reactor M. Barry 7/6/70 Electrochemical Society Meeting Los Angeles 569 California May 10-15, 1970 W. Kohler 6/30/70 Epitaxial Growth by Silane Decomposition 570 on Silicon - Boron Doped Oxide Structures E. Meieran 7/28/70 571 Scribing of Si and GaAs A. Engvall 7/30/70 Resist Scum Formation and Wafer Storage 572 R. Dyck 7/8/70 573 Self-Scanned Photosensor Arrays R. Olberg Correlation of Various Humidity Tests 8/3/70 574 R. Lane 7/24/70 575 /EPLOT/ and ECAP Output Combining and Plotting Program for use on Tymshare

TECHN	ICAL MEMORANDUMS	consent from Director's Unice	
NO.	TITLE	AUTHOR	DATE
576	Elimination of Aluminum Corrosion Around Gold Ball Bonds in Plastic Packages	I. A. Blech	8/7/70
577	Some Practical Aspects of Ellipsometry	C. Dell'Oca	9/1/70
578	Digital Photosensor	D. Hu	7/17/70
579	Deposition Pressure Rate Effects on Aluminum Film Properties	A. J. Learn	9/21/70
580	An Evaluation of the Zicon Photoresist Spray Coater	R. Judd A. Engvall	9/28/70
581	The Effect of Poly-Silicon Deposition Temperature on the Electrical Properties of Silicon-Gate MOSFET Devices	P. Fleming	9/29/70
582	1970 AIME Conference on Preparation and Properties of Electronic and Magnetic Materials for Computers	A. Yu	9/16/70
583	Electromigration in Al-Cu Metallization	I. Blech	10/9/70
584	Reduction of Al Corrosion Around Au Ball Bonds in Plastic Packages	I. Blech	10/9/70
585	100% Photomask Inspection	R. Weigand	10/19/70
586	Electrochemical Society Meeting, Atlantic City, October 1970	C. Dell'Oca	11/20/70
587	Feasibility of Repairing the Unibond Bump System on Ceramic Substrates	R. O'Neill	12/4/70
588	Evaluation of the K&S Automatic Mask Alignment (AUTOLIGN) Jig	D. Davis	2/12/71
589	Design Rules for Thin Film Resistors	R. Waits	1/26/71
590	Residual Surface Films on Single Crystal GaAs by Ellipsometry	R. Fairman	2/11/71
591	Large Capacity Resistance Heated Reactor	T. Kamins D. McCall J. Flood	3/8/71
592	Evaluation of Dough Molding Epoxy on Dual In-Line LIC Devices	R. Olberg	3/8/71
593	Contact Resistivity of Aluminum-Silicon (2%) Contacts on p- and n ⁺ Silicon	J. Archer	5/5/71

FAIRCHILD R&D

TECHNICAL MEMORANDUMS

0

0

C

- 33-

	ALRCHIL ECHNICA	D R&D IL MEMORANDUMS	COmmand Philade – Not reproduced or disclosed employees without express consent from Director's Of	to non- written
N	0.	TITLE	AUTHOR	DATE
55	94	Evaluation of Shipley Developer XP-7110	D. Davis R. Judd	5/20/71
5	95	Comparison of Six Moderately Priced Scanning Electron Microscopes Under \$50K	T. Cass	6/4/71
5	96	Video Non-Uniformity on First Two Elements of Self Scanned Arrays	L. Walsh	6/9/71
5	97	cancelled		
5	598	Electrochemical Society Meeting DCA, May 1971	E. Yim	5/10/71
···•	599	Polycrystalline Silicon Deposited from Dichlorosilane	T. Kamins	7/1/71
(600	Anodization of Aluminum to Inhibit Hillock Growth During High Temperature Processing	C. Dell'Oca A. Learn	7/9/71
(601	Proposal for Automatic Diameter Control for High Pressure Czochrolski Growth	R. Solomon	7/30/71
C	602	Temperature Coefficients of 2Kg/sq Si-Cr Resistors	R. Waits	8/2/71
	603	Channeling of Phosphorus Ions in Silicon	V. Reddi J. Sansbury	8/2/71
	604	cancelled		
(605	Comparative Evaluation of Epoxy Dough Mold with Commercial Epoxy, Silicone, Phenolic, and Diallylphthalate Molding Compounds	R. Olberg	8/11/71
		· · · · · · · · · · · · · · · · · · ·		
	697	Oxidation of Silicon Nitride	E. MacKenna	8/27/:

ð

1. 1

-34-

0

3.

COMPANY PRIVATE - Not to be reproduced or disclosed to non employees without express writter consent from Director's Office.

No.	Title	Author	Date
608	Electrochemical Society Meeting Cleveland, Ohio - October 1970	Dell'Oca, C.	11/1/71
609	Some Properties of Thick Dielectric Films	Barry, M./ Deal, B.	11/19/71
610	Low Voltage Reference Analysis and Design	Lane, R.	11/30/71
611	Effects of Crystalline Defects on Device Yield	Manoliu, J./ Meieran, E.	12/9/71
612	Photoresist Thickness Measurement by Visible Light Scan	Courtis, D./ Davis, D.	12/9/71
613	Defects in Gate Oxides	Sklar, M./ Person, B.	1/12/72
614	$Si_{3}N_{4}$ Processing-N _{st} and h _{FE} Correlation	MacKenna, E./ Blanchard, R.	1/20/72
615	A New Dielectric Isolation Technique for Bipolar Circuits Using Thin Single Crystal Silicon Films	Kamins, T.	2/23/72
616	Analysis of Motorola Metallization	Meieran, E./ Wandry, W./ Seiferling, J.	3/20/72
617	The Effect of Hydrogen and Steam on Diffusion of Boron and Phosphorus Through Thin Thermal Oxide Films	Sklar, M.	4/17/72
618	Double Crystal X-Ray Topography	Meieran, E.	5/18/72
619	The Effect of Cleaning on the Dielectric Breakdown of Thin Thermal Oxides on Non-Epitaxial Silicon	Sklar, M.	5/31/72
620	"STRIPIT" Plastic Stripping Agent	Olberg, R.	8/18/72
621	Diffusivity Summary of B, Ga, P, As and Sb in Si 0_2	Deal, B.	1/12/73
622	Photoresist Study of Kodak MR 747 vs Hunt Waycoat Type II	Neuman, R.	8/21/73
623	Design & Operation of Buried Channel Charge-Coupled Devices	Kim, C.	9/13/73

FAIRCHILD R&D TECHNICAL MEMORANDUMS

1.0

COMPANY PRIVATE — Not to be reproduced or disclosed to nonemployees without express written consent from Director's Office.

ľ		TITLE	AUTHOR	DATE
	<u>NO.</u> 624	Correlation of Dark Current Spikes in Charge Coupled Area Imaging Devices with Stacking	E. MacKenna	12/4/73
	625	Fault-Type Crystallographic Defects Minimization of Q ₀ During Not Substrate	D. Hess	3/1/74
	626	Aluminum Evaporation		
	627	Characteristics of SiSiO ₂ Interfaces Beneath Thin Silicon Films Defined by Electrochemical Etching	T. Kamins	3/29/74
	628	Electrochemical Society Meeting, San Francisco, May 13-17, 1974	B. Deal	6/3/74
	629	Spin-On Dry Adhesive for Epoxy Die Attach	R. Olberg J. Bozarth	6/6/74
	630	Gordon Research Conference on MIS Systems	D. Hess	9/13/7
)	631	Effect of Low Temperature Steam Oxidations on the Threshold of Isoplanar Oxides and on the Resulting Oxide Thickness Increase on Thin (1400 Å to 1700 Å) Oxides	D. Hess	9/24/7
	632	Characterization of the Dupont Sylek 201, Nickel-Boron Electroless Plate	S. Feltham	9/25/7
I.	633	Effect of Tegal Plasma Photoresist Asher on Oxide Charges	D. Hess	11/7/7
	634	Aluminum Corrosion in Plastic Packages. II. The Effect of Mixing and Postcuring of DM-6 and of the Use of Junction Coatings on Moisture Induced Corrosion Failures	R. Olberg	1/25/7
	635	Improvement of the Diffusion Barrier Properties of RF Sputtered Ti:W	R. Nowicki	9/22/1

FAIRCHILD COMPANY PRIVATE

Not to be reproduced or disclosed to nonemployees without express written consent from Director of R & D.

FAIRCHILD R&D TECHNICAL MEMORANDUMS

.

	NO.	TITLE	AUTHOR		DATE	
	636	Electrochemical Society Meeting, Dallas Texas, October 1975		Deal Hess	10/24/75	
	637	Determination of Hydrogen Peroxide in Sulfuric-Peroxide Clean Solution	Β.	Wong	1/19/76	
	638	Quantitative Analysis of Phosphorus Concentration in Silicon Dioxide Films Using X-Ray Fluorescence	R.	McDonald	2/18/76	
	639	LSI Metallization	Α.	Learn	3/10/76 .	
	640	Investigation of Blister Formation at the Si/SiO ₂ Interface During Thermal Oxi- dation of Silicon in HCP/O ₂ Atmospheres	D.	Hess	3/19/76	
	641	Electrochemical Society Meeting, Washington DC, May 1976		Deal. Hess	5/28/76	
•	642	Effect of Low Temperature Plasma Deposited Silicon Nitride as a Protective Barrier to Moisture Induced Aluminum Corrosion	R.	Olberg	6/10/76	
	643	18th Electronic Materials Conference, Salt Lake, Utah, June 1976	D.	Baylis	8/13/76	
	644					
	645	R&D Materials Analysis Lab	R.	McDonald	1/28/77	
	646	Important Developments Presented at the 1977 IITR SEM Symposium Relevant to Fairchild Activities	R.	McDonald	7/22/77	
	647	Dose Control and Uniformity Problems in Ion Implants with Doubly Ionized Species	J.	Pierce	8/26/77	
	648	Soft Bit Failures in CCD RAM's Due to Energetic Nuclear Particles		Pierce STRICTED I	3/27/78 DISTRIBUTION	
	649	The Scaling of NMOS	Ρ.	P.A. Crossley 11/1/78		
	650 ·	A Review of Current Interconnection Technology	W.	Lehrer	12/12/78	
	651	Stat-of-the Art of Semiconductor Surface Annealing	r.	. Delfino	7/25/79	
	651A	BibliographyChlorine Oxidation of Silicon	B	. Deal	9/19/79	

-	1.4.3	A . T. T. M. M. MANNER MARINE AND A MARINE A MARINE AND A			
1	тм652	Implementation of Processing Simulation Programs Suprem II (Verson O3) & Sample	Mruzki/M. Suaya, R.	10/19/79	1539
	TM 653	BibliographyPlasma Etching	Keyser, T. Péerce, J.	10/25/79	1537
E	TM 654	Electromigration in narrow aluminum alloy lines: preliminary results	Thomas, M. Pierce, J.	1/12/80	1540
	TM 655	Surface annealing bibliography addendum	Delfino, M.	1/25/80	1541
	TM 656.	Three techniques for determining the depth of deep and shallow juctions	S. Justi/ J. Bravman	1/30/80	1542
	TM 657	Gettering Bibliography	Delfino, M.	3/20/80	1543
	TM 658	A Self-Aligned Single Pixel Antiblooming Structur for CCD Image Sensors	Farrier, M.G. Dyck, R.	7/18/80	1545
	TM659	Surface Annealing Bibliography Addendum 11	Delfino, M.	8/29/80	1549
	TM 660	Investigation of Vertical Register Electrode Shorting in the CCD 2120 Area Imaging Device	Skåar, M.	8/29/80	1548
	TM 661	Stacking Fault Generation & Elimination	Husher, J.	11/4/80	1550
	TM 662	256K CCD Memory Design: Redundancy & Partial consideration	Venkateswaran,	к. 11/5/81	1555
	TM 663	PHOSPHOSILICATE GLASS BIBLIOGRAPHY	DELFINO, M - Reifsteck, T. Lie. L. N.	1/22/81 A	1553
1	TM 664	X-ray Lithography Bibliography	Cagan, M	2/4/81	1554
/	TM 666	Laser Activated Flow of Phosphosilicate Glass	Delfino, M Reifstack, t.a	5/11/81	1560
	•TM 665	DMOS Fower Transistors	Patel, V.	4/29/81	1561
	TM 667	Bibliography: Carrier Trapping in Thermal SiO ₂	Westphal, S. Razouk, R.	5/21/81	1562
	TM 668	A System For The Automatic Wafer Mapping Of Sheet Resistance	A. A. Milgram	6/2/81	1563
	T¥ 669	Surface Annealing Bibliography Addendumm II	Delfino, M	8/13/81	1566
	¥ TM 670	BibliographyThermal Oxidation of Poly- crystalline Silicon	L.N. LIE R.R. Razouk	9/18/81	1569
-	TM 671,	Monitoring ION Implantation	A. A. Milgram	11/3/81	1570
-	TM 672	BibliographyLift-Off Process	A. A. Milgram	11/6/81	1571
					15/1

2.50	*				1
1	TM 673	The Glassy State and Germano-Silicate Glass	Asif Iqbal	11/16/81	1572
1	TM.675	Lift-off Process for Achieving Fine Line Metallization Part I	A. Milgram	11/23/81	1573
	Tm 674		Deal, Bruce and Barry, Michael	11/19/81]574
	TM 676	Bibligraphy Portable Conformable Masking (PCM) Process	M. Cagan P. Leitner	1/8/82	1575
	TM 677	A High Resolution Trilevel Photolithographic Porcess	M. Cagan T Keyser	12/18/81	1576
	TM 680	Residual Gas Analysis of Dupont Polyimide PI-2555	M. R. Cagan J.A. Major	1/22/82	1577
	TM 679	Highlights of Semiconductor Interface Specialists Conf. New Orleans, La,Dec.2-5,'8	Bruce Deal Juliana Manoli Sylvia Westpha		1579
	TM 678	PLASMA ETCHING OF VIAS IN PHOSPHORUS-DOPED CVD ST02	D. HANSON t. Keyser J. Pierce	1/12/82	1580
	TM 681	Swiching elements for LCD devices	Milgram, A.	3/11/82	1581
	TM 682	HIGHLIGHTS OF THE ASTM SYMPOSIUM ON SILICON PROCESSING, SAN JSOE, CA. JAN. 19-22, 1982	W.M. BULLIS_/	3/26/82	1586
¥	TM 683	LOCAL OXIDATION OF SILICON METHODS FOR MINIMAL LATERAL OXIDATION	PRESSACCO,S RAZOUK, REDA	5/25/82	1589
	TM 684	Lift-Off process for achieving fine line metallization Part II	Milgram, A,	4/23/82	1587
	TI: 685	cancelled.			
	TM 686	Thermal resistance calculations of copper lead frame in a standard 40 lead P.D.I.P.	Harrah, S.	10/82	1594
	T* 627	Initial aluminum ball bonding experiments	Harrah, S.	10/82	1595
	TM 688	Modeling of Static Parameters in Vertical DMOS Power Transistor	Patel, V.	11/22/82	1596 •
	TM 689	Current Trends in Thermal Oxidation in VLSI Figures	Deal, D.	12/13/82	1597
			and the second		

3

ł